

**IN THE TITLE:**

Please amend the title as follows:

A METHOD OF PREPARING A POLY-CRYSTALLINE SILICON FILM

**IN THE SPECIFICATION:**

At the top of the first page, under the title, please insert the paragraph as follows:

**CROSS-REFERENCE TO RELATED APPLICATIONS**

This is a Divisional Application of U.S. Application No. 09/468,217, filed December 20, 1999, which is a CIP of U.S. Application No. 09/152,256, filed September 14, 1998, now U.S. Patent No. 6,099,918, both of which are based upon and claims the benefit of priority from prior Japanese Patent Application No. 09-260303, filed September 25, 1997.